

**UTC** UNISONIC TECHNOLOGIES CO., LTD

## 2N7002W

Preliminary

**Power MOSFET** 

# 300mA, 60V N-CHANNEL **POWER MOSFET**

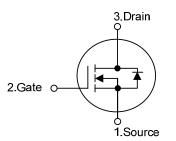
#### DESCRIPTION

The UTC 2N7002W uses advanced technology to provide excellent R<sub>DS(ON)</sub>, low gate charge and operation with low gate voltages. This device is suitable for use as a load switch or in PWM applications.

#### **FEATURES**

- \* High Density Cell Design for Low R<sub>DS(ON)</sub>.
- \* Voltage Controlled Small Signal Switch
- \* Rugged and Reliable
- \* High Saturation Current Capability



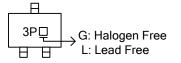


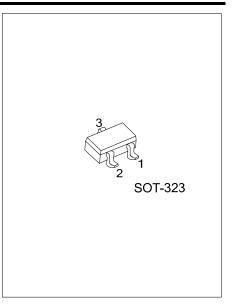
#### ORDERING INFORMATION

Ordering Number		Deekege	Pin Assignment			Dealing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
2N7002WL-AL3-R	2N7002WG-AL3-R	SOT-323	S	G	D	Tape Reel	

2N7002WG-AL3-R	(1)Packing Type	(1) R: Tape Reel
	(2)Package Type	(2) AL3: SOT-323
	(3)Halogen Free	(3) G: Halogen Free, L: Lead Free

### MARKING





## ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C, unless otherwise specified.)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V <sub>DSS</sub>	60	V	
Drain-Gate Voltage (R <sub>GS</sub> ≤1MΩ)		V <sub>DGR</sub>	60	V	
Gate Source Voltage	Continuous	N/	±20	V	
	Non Repetitive(t <sub>P</sub> <50µs)	V <sub>GSS</sub>	±40	v	
Drain Current	Continuous	I.	300	— mA	
	Pulsed	I <sub>D</sub>	800		
Power Dissipation		D-	200	mW	
Derated Above 25°C		P <sub>D</sub>	1.6	mW/°C	
Junction Temperature		TJ	+ 150	°C	
Storage Temperature		T <sub>STG</sub>	-55 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ <sub>JA</sub>	625 (Note1)	°C/W	

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS		·					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, Ι <sub>D</sub> =10μΑ	60			V	
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V			1	μA	
Gate-Source Leakage Current	I <sub>GSSF</sub>	V <sub>GS</sub> =20V, V <sub>DS</sub> =0V			100	nA	
Gale-Source Leakage Current	I <sub>GSSR</sub>	V <sub>GS</sub> =-20V, V <sub>DS</sub> =0V			-100	nA	
ON CHARACTERISTICS (Note2)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_D = 250 \mu A$	1	2.1	2.5	V	
Drain-Source On-Voltage	V <sub>DS (ON)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> =300mA		0.6	3.75	V	
Dialit-Source Off-voltage		V <sub>GS</sub> = 5.0V, I <sub>D</sub> =50mA		0.09	1.5		
	_	V <sub>GS</sub> =10V, I <sub>D</sub> =300mA ,T <sub>J</sub> =125°C			13.5	Ω	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	V <sub>GS</sub> =5.0V, I <sub>D</sub> =50mA			7.5	Ω	
DYNAMIC CHARACTERISTICS		·					
Input Capacitance	CISS	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V,f=1.0MHz		20	50	pF	
Output Capacitance	Coss			11	25	pF	
Reverse Transfer Capacitance	C <sub>RSS</sub>			4	5	pF	
Turn-On Time	t <sub>on</sub>	V <sub>DD</sub> =30V, R <sub>L</sub> =150Ω, I <sub>D</sub> =200mA, V <sub>GS</sub> =10V, R <sub>GEN</sub> =25Ω			20	nS	
Turn-Off Time	t <sub>OFF</sub>	V <sub>DD</sub> =30V, R <sub>L</sub> =25Ω, I <sub>D</sub> =200mA, V <sub>GS</sub> =10V, R <sub>GEN</sub> =25Ω			20	nS	
DRAIN-SOURCE DIODE CHARACTE	RISTICS AN	ID MAXIMUM RATINGS	•				
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, Is=300mA (Note)		0.88	1.5	V	
Maximum Pulsed Drain-Source Diode Forward Current	I <sub>SM</sub>				0.8	А	
Maximum Continuous Drain-Source Diode Forward Current	ls				300	mA	

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch. Minimum land pad size.

2. Pulse Test: Pulse Width≤300µs, Duty Cycle≤2.0%



## ■ TEST CIRCUIT AND WAVEFORM

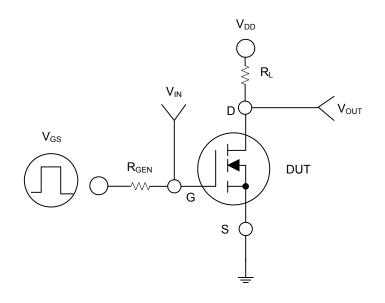


Fig. 1

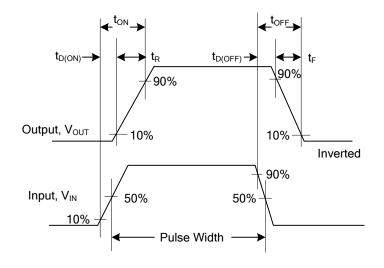


Fig. 2 Switching Waveforms

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